

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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Dual P-Channel MOSFET

-60V, -12A, $68m\Omega$

FEATURES

- Fast switching
- · Low thermal resistance package
- Low profile package
- Pb-free plating
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

Δ	D	D	C	Δ	T	n	N

- Power Supply
- Motor Control

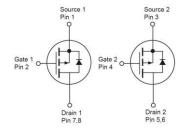
KEY PERFORMANCE PARAMETERS					
PARA	METER	VALUE	UNIT		
,	/ _{DS}	-60	V		
R _{DS(on)}	V _{GS} = -10V	68			
(max)	V _{GS} = -4.5V	110	mΩ		
	$\overline{Q_g}$	16.4	nC		











Dual P-Channel MOSFET

Note: MSL 1 (Moisture Sensitivity Level) per J-STD-020

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)					
PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-Source Voltage	V_{DS}	-60	V		
Gate-Source Voltage	V_{GS}	±20	V		
Continuous Drain Current (Note 1)	$T_C = 25^{\circ}C$	l _D	-12	А	
Continuous Drain Current	$T_C = 100$ °C		-8		
Pulsed Drain Current (Note 2)	I _{DM}	-48	Α		
Total Power Dissipation @ T _C = 25°C	P_{DTOT}	3.5	W		
Single Pulsed Avalanche Energy (Note 3)	E _{AS}	7.2	mJ		
Single Pulsed Avalanche Current (Note 3)	I _{AS}	12	Α		
Operating Junction and Storage Temperat	T_J,T_STG	- 55 to +150	°C		

THERMAL PERFORMANCE					
PARAMETER	SYMBOL	LIMIT	UNIT		
Junction to Case Thermal Resistance	R _{eJC}	4.5	°C/W		
Junction to Ambient Thermal Resistance	R_{\ThetaJA}	85	°C/W		

Notes: $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances. The case thermal reference is defined at the solder mounting surface of the drain pins. $R_{\Theta JA}$ is guaranteed by design while $R_{\Theta CA}$ is determined by the user's board design. $R_{\Theta JA}$ shown below for single device operation on FR-4 PCB in still air

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ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static (Note 4)		1			•	1
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = -250\mu A$	BV _{DSS}	-60			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	$V_{GS(TH)}$	-1.2	-1.6	-2.5	V
Gate Body Leakage	$V_{GS} = \pm 20V, V_{DS} = 0V$	I _{GSS}			±100	nA
7 0	$V_{DS} = -60V, V_{GS} = 0V$				-1	μΑ
Zero Gate Voltage Drain Current	V _{DS} = -48V, Tc = 125 ^o C	l _{DSS}			-10	
	$V_{GS} = -10V, I_D = -6A$	_		54	68	mΩ
Drain-Source On-State Resistance	$V_{GS} = -4.5V, I_D = -3A$	$R_{DS(on)}$		90	110	
Forward Transconductance	$V_{DS} = -10V, I_{D} = -6A$	g _{fs}		8.5		S
Dynamic (Note 5)				•	•	
Total Gate Charge	$V_{DS} = -30V, I_{D} = -6A,$ $V_{GS} = -10V$	Q_g		16.4		nC
Gate-Source Charge		Q_gs		2.8		
Gate-Drain Charge		Q_{gd}		3.6		
Input Capacitance		C _{iss}		870		
Output Capacitance	$V_{DS} = -30V, V_{GS} = 0V,$	C _{oss}		70		pF
Reverse Transfer Capacitance	f = 1.0MHz	C _{rss}		42		
Switching (Note 6)	-					1
Turn-On Delay Time		t _{d(on)}		8.3		
Turn-On Rise Time	$V_{DD} = -30V, I_{D} = -1A,$	t _r		42.4		
Turn-Off Delay Time	$R_{GEN} = 6\Omega$	t _{d(off)}		64.6		ns
Turn-Off Fall Time		t _f		16.4]
Source-Drain Diode (Note 4)				•	•	
Maximum Continuous Drain-Source		1			-12	Α
Diode Forward Current	Integral reverse diode	I _S			-12	
Maximum Pulse Drain-Source	in the MOSFET	I _{SM}			-48	Α
Diode Forward Current), ov. 1	_				
Diode-Source Forward Voltage	$V_{GS} = 0V, I_{S} = -1A$	V_{SD}			-1	V

Notes:

- 1. Current limited by package
- 2. Pulse width limited by the maximum junction temperature
- 3. L = 0.1 mH, $I_{AS} = -12 A$, $V_{DD} = -25 V$, $R_G = 25 \Omega$, Starting $T_J = 25 ^{\circ} C$
- 4. Pulse test: PW \leq 300 μ s, duty cycle \leq 2%
- 5. For DESIGN AID ONLY, not subject to production testing.
- 6. Switching time is essentially independent of operating temperature.

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ORDERING INFORMATION (EXAMPLE)

PART NO.	PACKAGE	PACKING
TSM680P06DPQ56 RLG	PDFN56 Dual	2,500pcs / 13"Reel

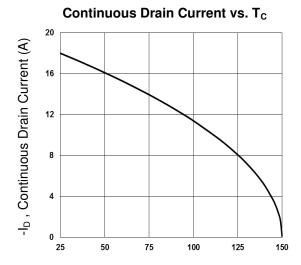
Note:

- 1. Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- 2. Halogen-free according to IEC 61249-2-21 definition

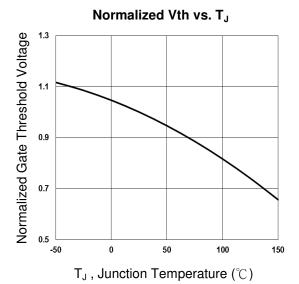


CHARACTERISTICS CURVES

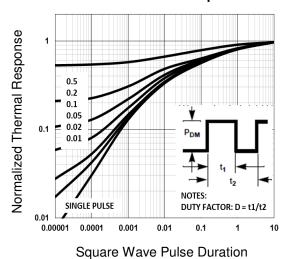
(T_C = 25°C unless otherwise noted)



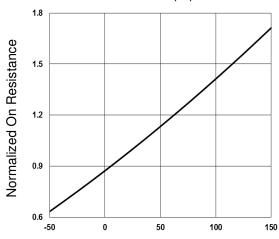
T_C, Case Temperature (°C)



Normalized Transient Impedance

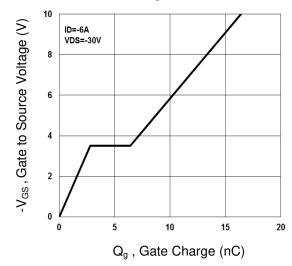


Normalized R_{DS(ON)} vs. T_J

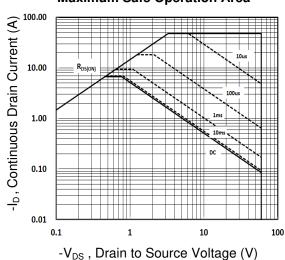


T_J, Junction Temperature (°C)





Maximum Safe Operation Area

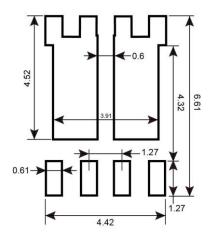




PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

PDFN56 Dual 4.90 ±0.10 5.75 ±0.05 1.00 ±0.10 1.00 ±0.10

SUGGESTED PAD LAYOUT (Unit: Millimeters)



R =Apr

MARKING DIAGRAM



Y = Year Code

M = Month Code for Halogen Free Product

O =Jan P =Feb Q =Mar

S = May T = Jun U = Jul V = Aug

W = Sep X = Oct Y = Nov Z = Dec

L = Lot Code $(1\sim9, A\sim Z)$

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